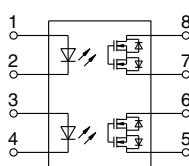
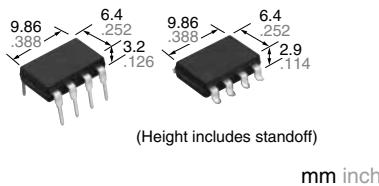


**Normally closed type
with reinforced insulation**

PhotoMOS®

**GE 2 Form B
(AQW414EH)**



RoHS compliant

FEATURES

1. Reinforced insulation of 5,000 V

More than 0.4 mm internal insulation distance between inputs and outputs. Conforms to EN41003, EN60950 (reinforced insulation).

2. Applicable for 2 Form B use as well as two independent 1 Form B use

3. Controls low-level analog signals

PhotoMOS feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.

4. High sensitivity and high speed response

Can control max. 0.13 A load current with 5 mA input current. Fast operation speed of Typ. 0.8 ms.

5. Low-level off state leakage current

TYPICAL APPLICATIONS

- Modem
- Telephone equipment
- Electricity, plant equipment
- Security equipment
- Sensing equipment

TYPES

I/O isolation voltage	Output rating*	Load voltage	Load current	Package	Part No.			Packing quantity			
					Through hole terminal		Surface-mount terminal				
					Tube packing style		Tape and reel packing style				
AC/DC dual use	Reinforced 5,000 Vrms	400 V	100 mA	DIP8-pin	AQW414EH	AQW414EHA	AQW414EHAX	AQW414EHAZ	1 tube contains : 50 pcs. 1 batch contains: 500 pcs.	1,000 pcs.	

*Indicate the peak AC and DC values.

Note: The surface mount terminal shape indicator "A" and the packing style indicator "X" or "Z" are not marked on the device.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

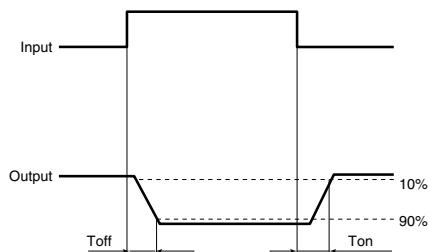
Item		Symbol	AQW414EH(A)		Remarks
Input	LED forward current	I _F	50mA		
	LED reverse voltage	V _R	5V		
	Peak forward current	I _{FP}	1A	f =100 Hz, Duty factor = 0.1%	
	Power dissipation	P _{in}	75mW		
Output	Load voltage (peak AC)	V _L	400 V		
	Continuous load current	I _L	0.1 A (0.13 A)	Peak AC, DC (): in case of using only 1 channel.	
	Peak load current	I _{peak}	0.3 A	100 ms (1 shot), V _L = DC	
	Power dissipation	P _{out}	800mW		
Total power dissipation		P _T	850mW		
I/O isolation voltage		V _{iso}	5,000 Vrms		
Ambient temperature	Operating	T _{opr}	-40 to +85°C -40 to +185°F	(Non-icing at low temperatures)	
	Storage	T _{stg}	-40 to +100°C -40 to +212°F		

GE 2 Form B (AQW414EH)

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item		Symbol	AQW414EH(A)	Condition
Input	LED operate (OFF) current	Typical Maximum	I _{off} 1.3mA 3.0mA	I _L =Max.
	LED reverse (ON) current	Minimum Typical	I _{on} 0.4mA 1.2mA	I _L =Max.
	LED dropout voltage	Typical Maximum	V _F 1.25 (1.14 V at I _F =5mA) 1.5V	I _F =50mA
Output	On resistance	Typical	R _{on} 26Ω	I _F =0mA
		Maximum	35Ω	I _L =Max. Within 1 s
	Off state leakage current	Maximum	I _{leak} 10μA	I _F =5mA V _L =Max.
Transfer characteristics	Operate (OFF) time*	Typical Maximum	T _{off} 0.8ms 3.0ms	I _F =0mA→5mA I _L =Max.
	Reverse (ON) time*	Typical Maximum	T _{on} 0.2ms 1.0ms	I _F =5mA→0mA I _L =Max.
	I/O capacitance	Typical Maximum	C _{iso} 0.8pF 1.5pF	f =1MHz V _B =0V
	Initial I/O isolation resistance	Minimum	R _{iso} 1,000MΩ	500V DC

*Operate/Reverse time



3. Recommended operating conditions (Ambient temperature: 25°C 77°F)

Please use under recommended operating conditions to obtain expected characteristics.

Item	Symbol	Number of used channels	Min.	Max.	Unit
AQW414EH(A)	LED current	I _F	5	30	mA
	Load voltage (Peak AC)	V _L	—	320	V
	Continuous load current	I _L	1ch 2ch	0.13 0.1	A

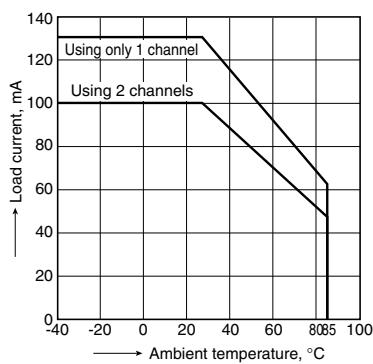
■ These products are not designed for automotive use.

If you are considering to use these products for automotive applications, please contact your local Panasonic Corporation technical representative.

REFERENCE DATA

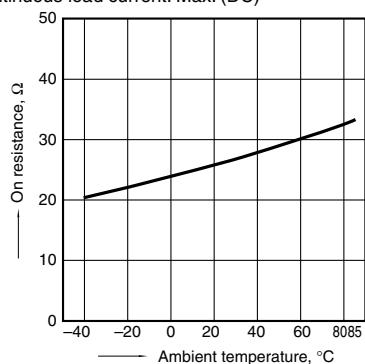
1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40 to +85°C
-40 to +185°F



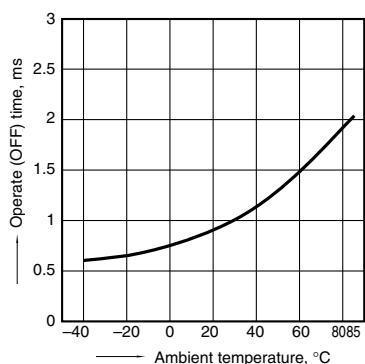
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
LED current: 0 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



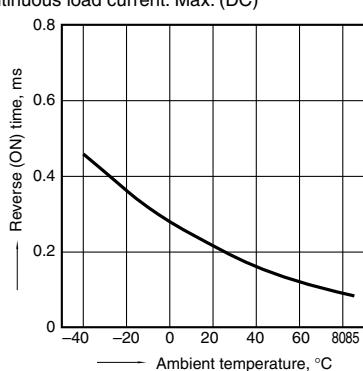
3. Operate (OFF) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



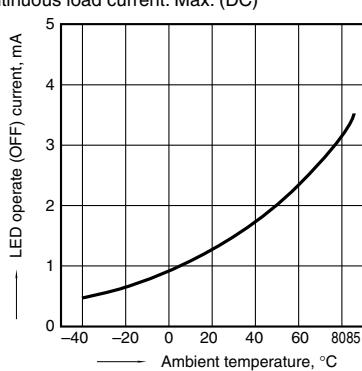
4. Reverse (ON) time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC);
Continuous load current: Max. (DC)



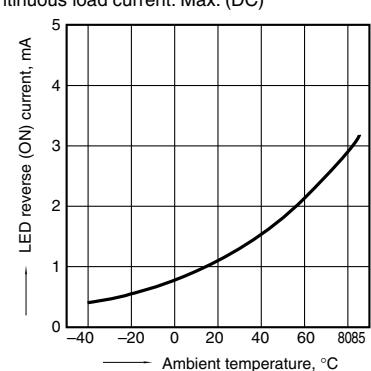
5. LED operate (OFF) current vs. ambient temperature characteristics

Load voltage: Max. (DC);
Continuous load current: Max. (DC)



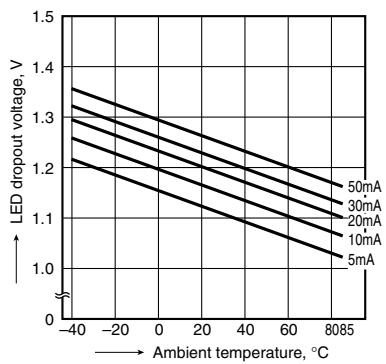
6. LED reverse (ON) current vs. ambient temperature characteristics

Load voltage: Max. (DC);
Continuous load current: Max. (DC)



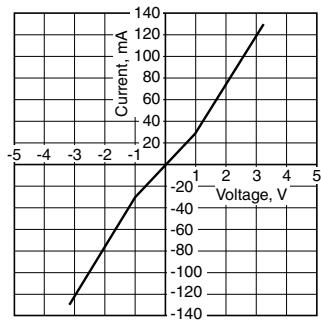
7. LED dropout voltage vs. ambient temperature characteristics;

LED current: 5 to 50 mA



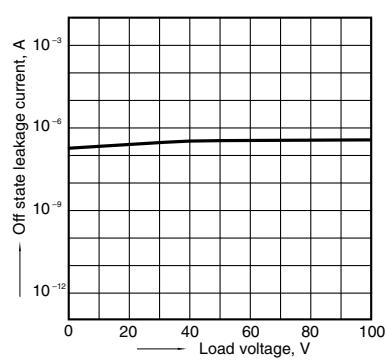
8. Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 5 and 6, 7 and 8;
Ambient temperature: 25°C 77°F



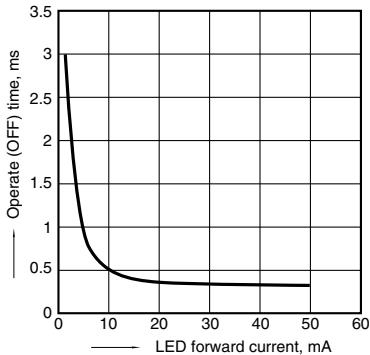
9. Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
Ambient temperature: 25°C 77°F



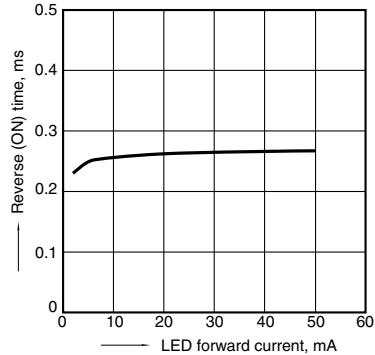
10. Operate (OFF) time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
Load voltage: Max. (DC); Continuous load current:
Max. (DC); Ambient temperature: 25°C 77°F



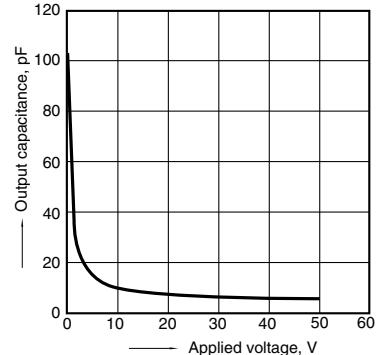
11. Reverse (ON) time vs. LED forward current characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
Load voltage: Max. (DC); Continuous load current:
Max. (DC); Ambient temperature: 25°C 77°F



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8;
Frequency: 1 MHz; Ambient temperature: 25°C 77°F



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*Recognized in Japan, the United States, all member states of European Union and other countries.

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